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Bret C. Hess^a, Eric A. Forgý^a, Sergey Frolov^b, David D. Dick^b &
Zeev V. Vardeny^b

^a Physics Department, California State University, Fresno, CA, 93740

^b Physics Department, University of Utah, Salt Lake City, Utah,
84112

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EXCITON DYNAMICS IN SOLID C₆₀ AT HIGH PRESSURE

BRET C. HESS and ERIC A. FORGY

Physics Department, California State University, Fresno, CA 93740

SERGEY FROLOV, DAVID D. DICK, and ZEEV V. VARDENY

Physics Department, University of Utah, Salt Lake City, Utah 84112

Abstract

We have studied the singlet exciton decay by picosecond photoinduced absorption (PA) in films of C₆₀, under pressures up to 62 kbar. When excited at 2 eV, the exciton lifetime distribution broadens with pressure. A similar broadening occurs when changing the exciting wavelength at ambient pressure. This suggests that the lifetimes of the lowest-energy excitons do not depend upon hopping or tunneling between C₆₀ molecules. We see no evidence in the dynamics of the lowest energy excitons for the evolution of extended states or bands with pressure up to 60 kbar, even though we excite states well above the absorption edge.

INTRODUCTION

The dynamics of excitons in C₆₀ in solution have been extensively studied. The decay of singlet excitons in solution occurs with a lifetime of about 1 ns, and is governed by the crossover into triplet excitons with a much longer lifetime.^{1,2} However the nature of the electronic structure of the solid is still uncertain. In particular, the degree of coupling between molecules and the role of electronic correlation in this coupling is of particular interest. One-electron band structure calculations³ of the fcc solid C₆₀ suggest an energy gap of about 1.5 eV between narrow continuum bands of bandwidth $W \approx 0.4$ eV. Indeed, weak absorption is observed⁴ between 1.6 and 2 eV. However electron-electron interaction is important in C₆₀ solids. Photoemission and Auger experiments give an on-site Coulomb interaction $U = 1.6$ eV and a forbidden "gap" at 2.3 eV.⁵ With $U/W=4$, strongly localized Frenkel excitons are expected for the lowest electronic excited states, rather than band states or Wannier excitons.

Studying photoinduced absorption (PA) at 605 nm, Cheville and Halas⁶ reported a stretched-exponential decay in the picosecond time range. They attributed the PA decay to tunneling or hopping between localized electronic states.

In this work we have studied the singlet exciton decay in C₆₀ films as a function of pressure. Pressure studies have been of great interest in solid C₆₀ because of the opportunity to increase intermolecular coupling. The absorption edge,^{9,10} reflectivity edge,¹¹ and photoluminescence peak¹² are observed to redshift with pressure at rates of 5-14 meV/kbar. This gap reduction is widely interpreted as the formation and broadening of delocalized conduction and valence bands with pressure.

From the PA decay¹³ we find that the exciton dynamics from 300 fs to 3 ns change with pressure, but this change can be explained by a redshift in the distribution of localized singlet excitons across the excitation photon energy. The lack of a true pressure effect, even though the separation distance between C₆₀ molecules changes dramatically, suggests that the exciton dynamics cannot be limited by hopping or tunneling processes.⁶ The stretched-exponential and power-law decays observed over hundreds of picoseconds instead result from a distribution of molecular exciton recombination rates, independent of hopping.

EXPERIMENT

C₆₀ films from 99.9% pure powder were sublimated in a vacuum of less than 10⁻⁶ torr at a rate of about 3 Å/s from a quartz crucible near 450 °C. The film thickness was about 800 nm. The substrates were glass and 12 μm thick mylar sheets. Mylar has been used successfully as a thin-film substrate in a number of pressure studies.¹⁴ Pieces of C₆₀ film on mylar were cut to fit in a gasketed diamond anvil cell with deoxygenated alcohol and ruby chips. Measurements were taken at room temperature.

Two picosecond laser systems were used to measure the exciton dynamics by photoinduced absorption (PA), in which the change ΔT in the probe transmission T is measured as a function

of the probe delay time relative to a pump pulse. A colliding-pulse modelocked ring dye laser (CPM) was used for measurements at high pressure and fixed wavelength. Because the absorption increases with photon energy in the tail of the absorption, the laser was operated near 615 nm rather than the usual 620-630 nm, giving pulses from 150 to 300 fs in duration. For ambient pressure measurements at variable wavelength, we used a synchronously pumped dye laser with 5 ps resolution. For all experiments the photon densities per pulse were about 0.1 mJ/cm².

The transient PA in C₆₀ films is shown in Fig. 1 for pressures from 0 to 62 kbar. The PA signal represents an increase in the absorption ($\Delta\alpha > 0$) which is proportional to the photoexcited exciton density, due to larger transition probabilities to higher singlet exciton states $S_1 \rightarrow S_n$ than for the mostly forbidden lowest ground state absorption $S_0 \rightarrow S_1$.

The decay curve at ambient pressure (0 kbar) is well fitted by either a stretched-exponential form for the exciton population,

$$N(t) \sim \exp[-(t/\tau)^\beta] \quad (1)$$

where $\beta = 0.54$, and $\tau = 160$ ps, or by another decay form common to disordered systems¹²

$$N(t) \sim 1/[1 + (t/\tau)^\alpha] \quad (2)$$

where $\alpha = 0.83$, and $\tau = 87$ ps, which is the fit shown in Fig. 1 for 0 kbar. The two fits begin to differ noticeably only around 500 ps, where $t \gg \tau$. The stretched exponential values obtained at 615 nm differ somewhat from those reported by Cheville and Halas⁶ at 605 nm ($\beta = 0.42$, and $\tau = 43$ ps), but as we show later, these parameters depend on the details of the disorder distributions in the sample and hence on exciting wavelength.

With increasing pressure, both τ and α decrease, reflecting a broadening in the distribution of exciton lifetimes. By 28 kbar, the decay clearly approaches a power-law, $N(t) \sim (t/\tau)^{-\alpha}$, the asymptotic form of (2).

By 60 kbar, the CPM photon energy at 2 eV is well above the absorption threshold.¹¹ We observe a linear redshift¹¹ of $dE/dP = -7$ meV/kbar, similar to that reported⁸ (-5.5 meV/kbar) for a thicker film deposited directly on a diamond anvil.

Since pressure redshifts the absorption edge of solid C₆₀, we explored the possibility that the changes in the decay form were simply caused by the movement of different regions of the absorption tail across the fixed CPM photon energy. Fig. 2 shows the transient PA at varying photon energies in unpressed samples. These measurements on the sync pump system demonstrate that increasing photon energy at ambient pressure is similar to increasing pressure at a fixed wavelength at ambient pressure: both the stretched-exponential decay and the slow tail begin to converge to a power-law decay. Since the absorption band redshifts with pressure at a rate $dE/dP = -7$ meV/kbar, the 200 meV shift between the highest excitation energy (560 nm) and the lowest (615 nm) is equivalent to a redshift of the absorption band due to a pressure difference of about 30 kbar. The same decay exponent $\alpha = 0.3$ is found in the two “equivalent” cases: 560 nm at 0kbar, and 615nm at 28 kbar.

Cheville and Halas⁶ attributed the stretched-exponential decay to a distribution of tunneling or hopping rates between localized states. By 60 kbar, the inter-ball distance has been reduced by 30%, from 2.9 to 2.0 Å,^{14,15} and tunneling or hopping rates should be strongly affected. Instead, we observe that the changes with increasing pressure can be roughly imitated at ambient pressure by pumping and probing at higher photon energies. There is no substantial change in the distribution of exciton lifetimes with pressure. Instead, different portions of the distribution are probed as the distribution redshifts across the fixed CPM wavelength. The lack of a true pressure effect suggests that the exciton lifetime is not governed by dispersion in the hopping or tunneling rates between C₆₀ molecules. This is consistent with the finding that the PA decay is temperature independent.⁶ We conclude that the dispersion in the PA decay must be due to a distribution of exciton decay times among the excited molecules, rather than due to dispersive diffusion of excitations toward recombination centers.

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Figure Captions

Figure 1:

Decay of singlet excitons in a C₆₀ film at various pressures. The pump and probe wavelength was 615 nm. The curves are vertically offset for easier comparison. The dashed lines represent fits to $N(t) \sim 1/[1 + (t/\tau)^\alpha]$

Figure 2:

Decay of singlet excitons in a C₆₀ film pumped and probed at various wavelengths, at ambient pressure. The curves are vertically offset for easier comparison. The dashed line is a fit to a power-law decay, yielding an exponent $\alpha = 0.3$.



